

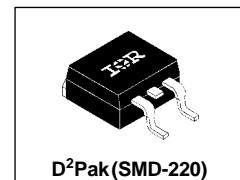
International IR Rectifier

PD-20561 05/98

8TQ...S SERIES

SCHOTTKY RECTIFIER

8 Amp



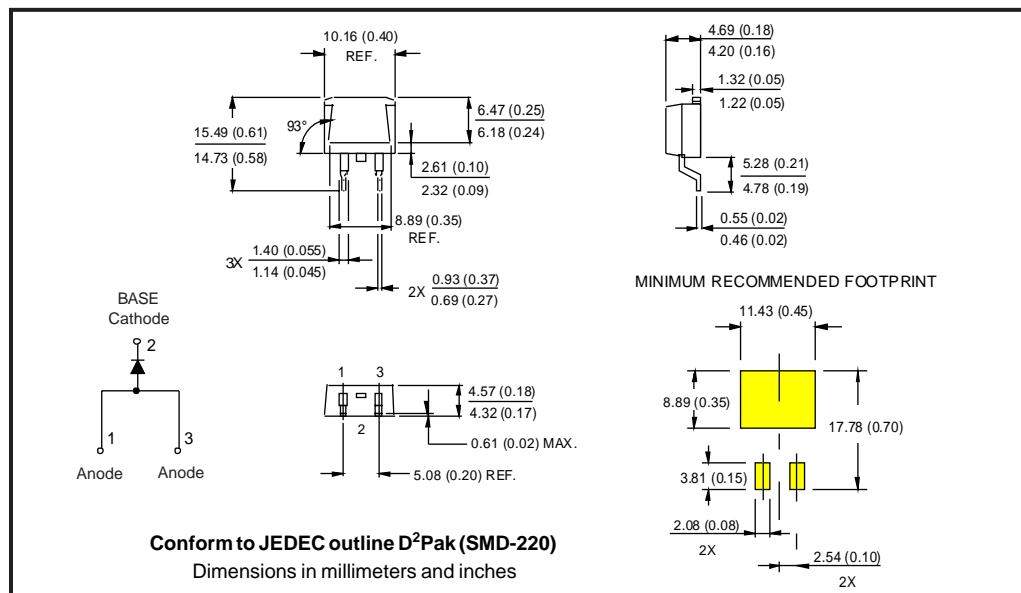
Major Ratings and Characteristics

Characteristics	8TQ...S	Units
I _{F(AV)} Rectangular waveform	8	A
V _{RRM} range	80 to 100	V
I _{FSM} @ tp=5 µs sine	850	A
V _F @ 8 Apk, T _J =125°C	0.58	V
T _J range	-55 to 175	°C

Description/Features

The 8TQ...S Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175° C T_J operation
- D²Pak (SMD-220) package
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	8TQ080S	8TQ100S
V_R Max. DC Reverse Voltage (V)	80	100
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	8TQ...S	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	8	A	50% duty cycle @ $T_c = 159^\circ\text{C}$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	850	A	5μs Sine or 3μs Rect. pulse
	230		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	7.50	mJ	$T_j = 25^\circ\text{C}$, $I_{AS} = 0.50$ Amps, $L = 60$ mH
I_{AR} Repetitive Avalanche Current	0.50	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_j max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	8TQ...S	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.72	V	$T_j = 25^\circ\text{C}$
	0.88	V	$T_j = 125^\circ\text{C}$
	0.58	V	$T_j = 25^\circ\text{C}$
	0.69	V	$T_j = 125^\circ\text{C}$
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	0.55	mA	$V_R = \text{rated } V_R$
	7	mA	$T_j = 125^\circ\text{C}$
$V_{F(TO)}$ Threshold Voltage	404	V	$T_j = T_j \text{ max.}$
r_t Forward Slope Resistance	10.89	mΩ	
C_T Max. Junction Capacitance	500	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	8	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs	

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	8TQ...S	Units	Conditions
T_j Max. Junction Temperature Range	-55 to 175	°C	
T_{stg} Max. Storage Temperature Range	-55 to 175	°C	
R_{thJC} Max. Thermal Resistance Junction to Case	2.0	°C/W	DC operation * See Fig. 4
wt Approximate Weight	2(0.07)	g(oz.)	
Case Style	D ² Pak (SMD-220)		JEDEC

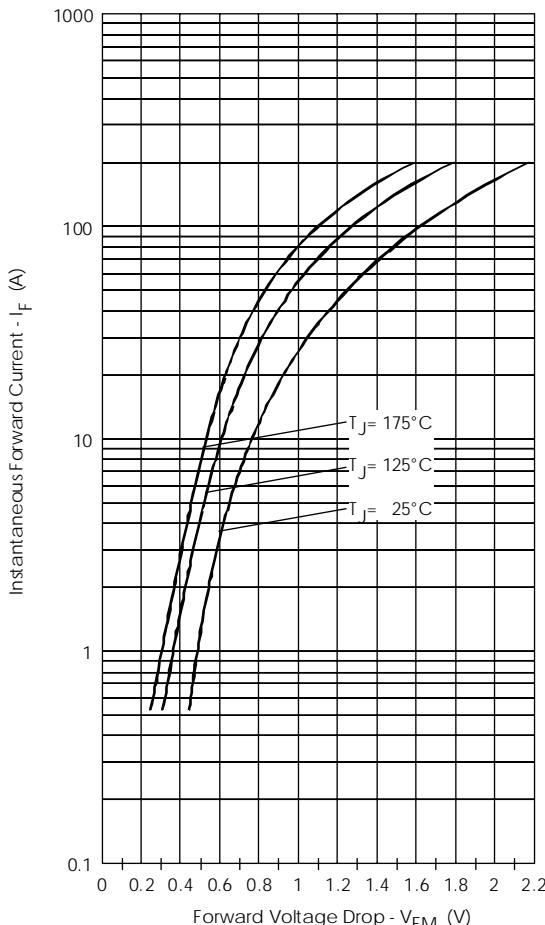


Fig.1-Maximum Forward Voltage Drop Characteristics

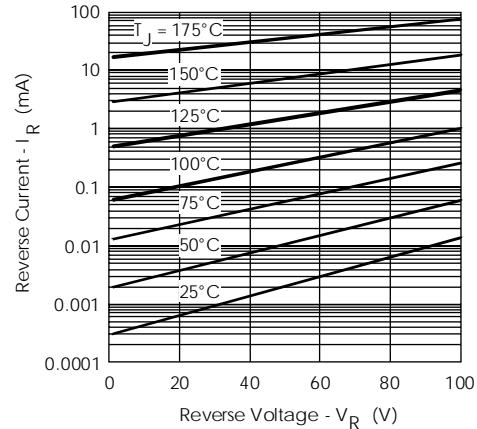


Fig.2-Typical Values of Reverse Current Vs. Reverse Voltage

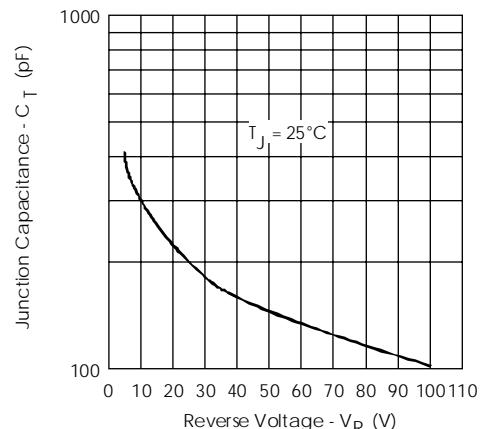


Fig.3-Typical Junction Capacitance Vs. Reverse Voltage

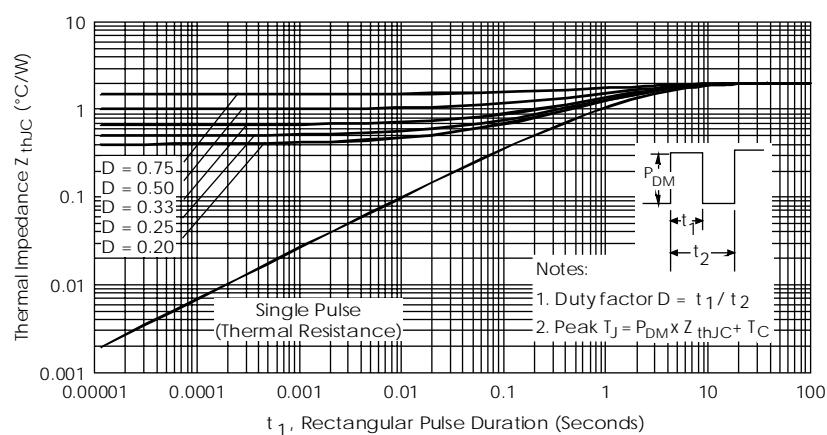


Fig.4-Maximum Thermal Impedance Z_{thJC} Characteristics

8TQ...S Series

PD-20561 05/98

International
IR Rectifier

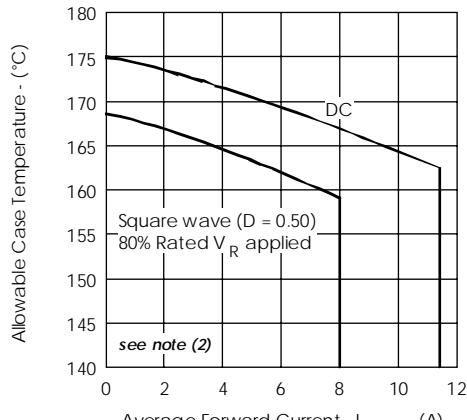


Fig.5-Maximum Allowable Case Temperature
Vs. Average Forward Current

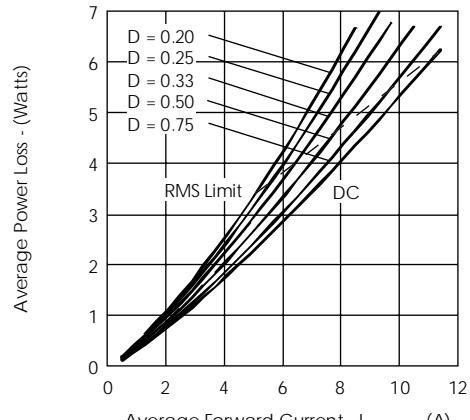


Fig.6-Forward Power Loss Characteristics

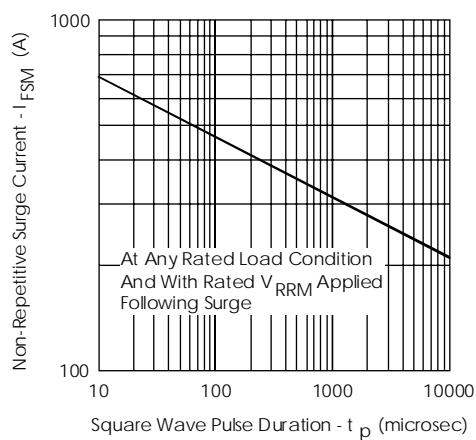


Fig.7-Maximum Non-Repetitive Surge Current

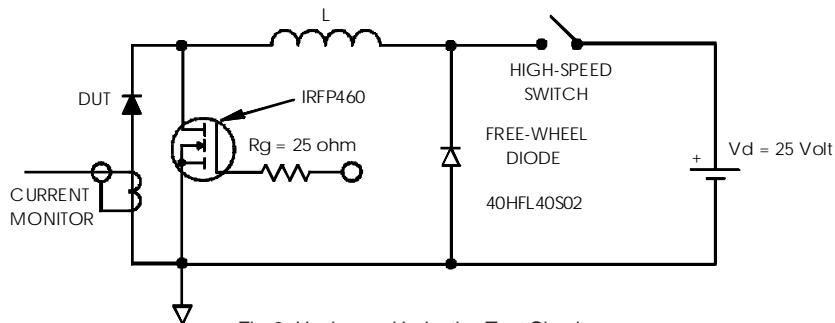
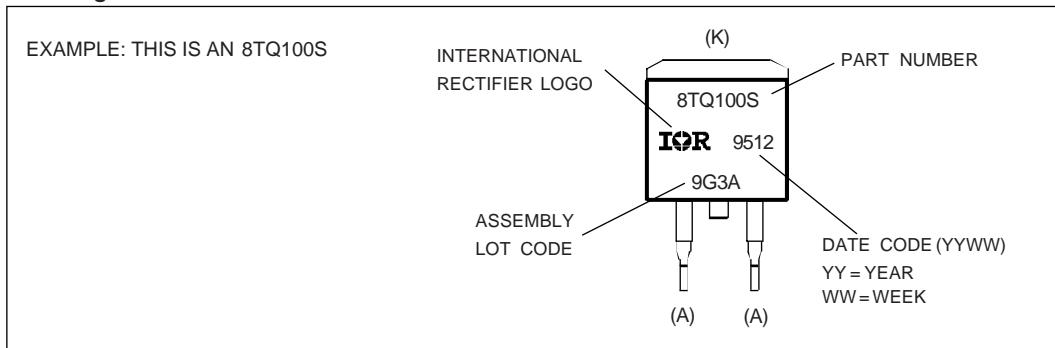


Fig.8-Unclamped Inductive Test Circuit

- (2) Formula used: $T_C = T_J - (P_d + P_{d,REV}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d,REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Marking Information



Tape & Reel Information

